

**IN THE CLAIMS**

Please substitute claims 1-27 with the following:

1-26 (Cancelled).

27. (Currently Amended) A solid-state image sensor comprising:

unit pixels each having a photoelectric conversion element for amplifying converting  
incident light into an electric signal charge and then storing the signal charge obtained through  
such photoelectric conversion;

an amplifying element for amplifying the an electric signal charge stored in from said  
photoelectric conversion element into an electric signal; and

a reset element for resetting said signal charge photoelectric conversion element, wherein  
said reset element is a depression type being a depletion transistor, and

wherein said amplifying element outputs said electric signal of a reset charge level and a  
signal charge level for correlated double sampling.